# V35PWM153

Vishay General Semiconductor

# High Current Density Surface-Mount TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.47$  V at  $I_F = 5$  A



www.vishay.com

## SlimDPAK (TO-252AE)



## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	35 A			
V <sub>RRM</sub>	150 V			
I <sub>FSM</sub>	260 A			
V <sub>F</sub> at I <sub>F</sub> = 35 A (T <sub>J</sub> = 125 °C)	0.71 V			
T <sub>J</sub> max.	175 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Single			

## FEATURES

- Very low profile typical height of 1.3 mm
- Trench MOS Schottky technology
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
   Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **TYPICAL APPLICATIONS**

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

## **MECHANICAL DATA**

**Case:** SlimDPAK (TO-252AE) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V35PWM153	UNIT	
Device marking code		V35PWM153		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	150	V	
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub> <sup>(1)</sup>	35	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	260	A	
Operating junction temperature range	T <sub>J</sub> <sup>(2)</sup>	-40 to +175	°C	
Storage temperature range	T <sub>STG</sub>	-55 to +175	°C	

Notes

<sup>(1)</sup> With infinite heatsink

<sup>(2)</sup> The heat generated must be less than the thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 





COMPLIANT HALOGEN

Revision: 29-Jan-2021

1

V35PWM153



www.vishay.com

# Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage	I <sub>F</sub> = 5.0 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.57	-	V
	I <sub>F</sub> = 17.5 A			0.77	-	
	I <sub>F</sub> = 35 A			0.94	1.05	
	I <sub>F</sub> = 5.0 A	T <sub>J</sub> = 125 °C		0.47	-	
	I <sub>F</sub> = 17.5 A			0.61	-	
	I <sub>F</sub> = 35 A			0.71	0.76	
Reverse current	V <sub>B</sub> = 100 V	T <sub>J</sub> = 25 °C	I <sub>R</sub> (2)	0.002	-	- mA
	v <sub>R</sub> = 100 v	T <sub>J</sub> = 125 °C		2.4	-	
	V <sub>B</sub> = 150 V	T <sub>J</sub> = 25 °C		-	0.2	
	v <sub>R</sub> = 150 v	T <sub>J</sub> = 125 °C		6	20	
Typical junction capacitance	4.0 V, 1 MHz		CJ	1420	_	pF

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V35PWM153	UNIT	
Typical thermal resistance	R <sub>0JA</sub> (1)(2)	65	°C/W	
	R <sub>0JM</sub> <sup>(3)</sup>	1.5		

## Notes

 $^{(1)}$  The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

 $^{(2)}$  Free air, mounted on recommended copper pad area; thermal resistance  $R_{\theta JA}$  - junction to ambient

<sup>(3)</sup> Mounted on infinite heat sink; thermal resistance  $R_{\theta JM}$  - junction-to-mount

ORDERING INFORMATION (Example)					
PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE E		BASE QUANTITY	DELIVERY MODE		
V35PWM153-M3/I	0.20	I	4500	13" diameter plastic tape and reel	
V35PWM153HM3/I <sup>(1)</sup>	0.20	l	4500	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified



# Vishay General Semiconductor

## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

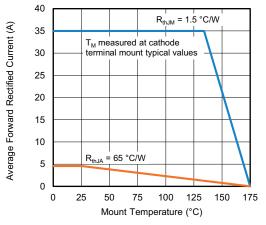


Fig. 1 - Maximum Forward Current Derating Curve

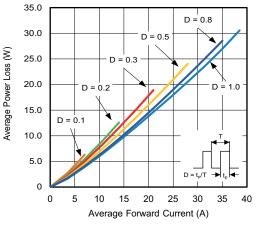


Fig. 2 - Forward Power Loss Characteristics

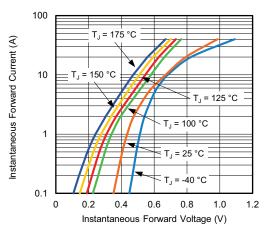


Fig. 3 - Typical Instantaneous Forward Characteristics

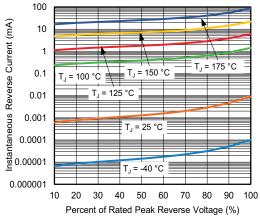


Fig. 4 - Typical Reverse Leakage Characteristics

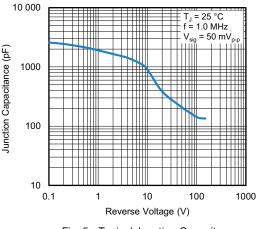


Fig. 5 - Typical Junction Capacitance

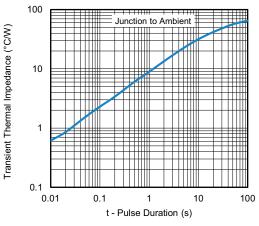


Fig. 6 - Typical Transient Thermal Impedance

Revision: 29-Jan-2021

3

Document Number: 98168

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

# Vishay General Semiconductor

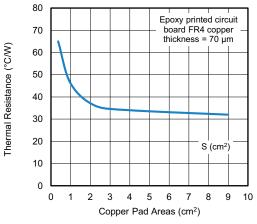
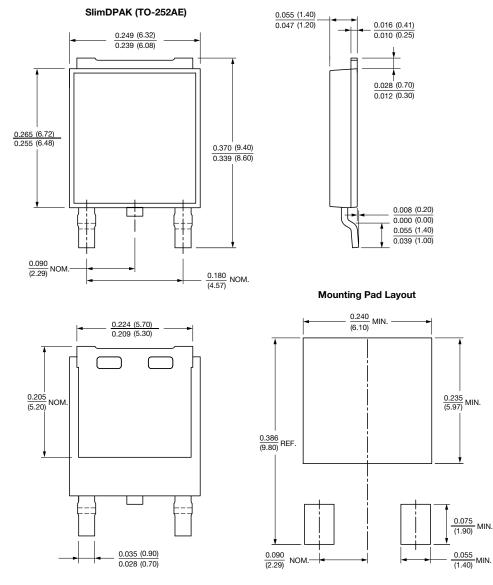


Fig. 7 - Typical Resistance Junction to Ambient vs. Copper Pad Areas



SHAY

www.vishay.com



# Revision: 29-Jan-2021 4 Document Number: 98168 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.